

Power Transistor (15V, 500mA)

Parameter	Value		
$V_{CEO}$	15V		
IC	500mA		

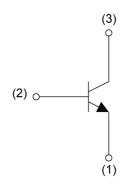
# Outline SMT3 (2) (3) (1) SOT-346

SC-59

### Features

1)Low  $V_{CE(sat)}$ . (Typ.8mV at  $I_C/I_B=10/1mA$ ) 2)Optimal for muting.

### •Inner circuit



- (1) Emitter
- (2) Base
- (3) Collector

# Application

**MUTING** 

### Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SD1757K	SMT3	2928	T146	180	8	3000	AA

# ● Absolute maximum ratings (T<sub>a</sub> = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	$V_{CBO}$	30	V
Collector-emitter voltage	V <sub>CEO</sub>	15	V
Emitter-base voltage	V <sub>EBO</sub>	6.5	V
Collector current	I <sub>C</sub>	500	mA
Power dissipation	P <sub>D</sub> *1	200	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Davanastav	Curah al	Conditions	Values			1.1
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = 50μA	30	-	-	V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1mA	15	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 50μA	6.5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 20V	-	-	500	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 4V	-	-	500	nA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA	-	100	400	mV
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = 3V, I <sub>C</sub> = 100mA	120	-	560	-
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5V, I <sub>E</sub> = -50mA, f = 100MHz	-	150	-	MHz
Output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0A, f = 1MHz	-	15	-	pF

### hFE values are calssified as follows:

rank	Q	R	S	-	-
h <sub>FE</sub>	120-270	180-390	270-560	-	-

<sup>\*1</sup> Each terminal mounted on a fererence land.

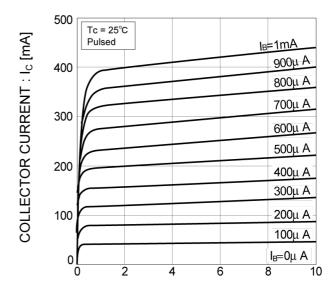
# ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

1000 Ta = 25°C 500 COLLECTOR CURRENT : I<sub>C</sub> [mA] V<sub>CE</sub> = 6V Pulsed 200 100 50 20 10 5 2 1 0.5 0.2 0.1 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8

BASE TO EMITTER VOLTAGE :  $V_{\text{BE}}\left[V\right]$ 

Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V<sub>CE</sub> [V]

Fig.3 DC Current Gain vs. Collector Current (I)

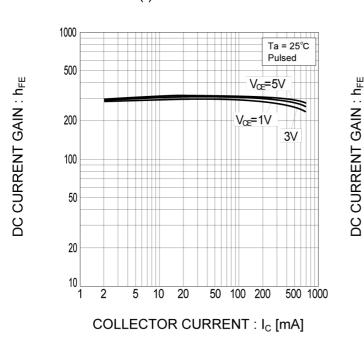
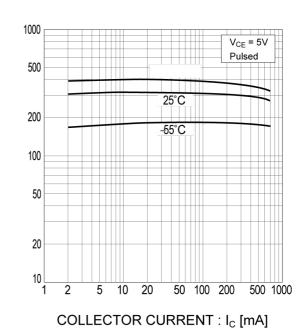


Fig.4 DC Current Gain vs. Collector Current (II)



### ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

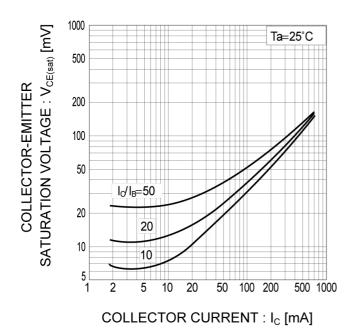


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

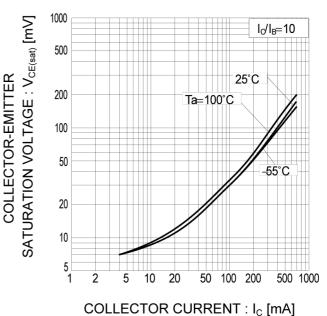


Fig.7 Collector-Emitter Saturation

Voltage vs. Collector Current (III)

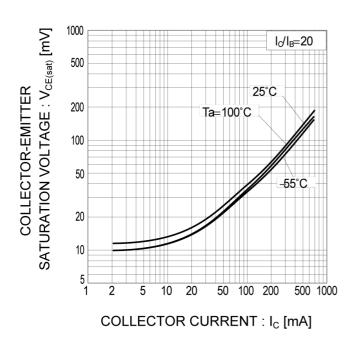
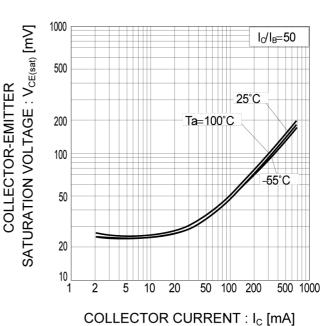


Fig.8 Collector-Emitter Saturation Voltage vs. Collector Current (IV)



# ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.9 Gain Bandwidth Product vs. Emitter Current

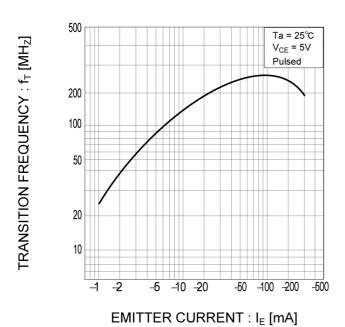
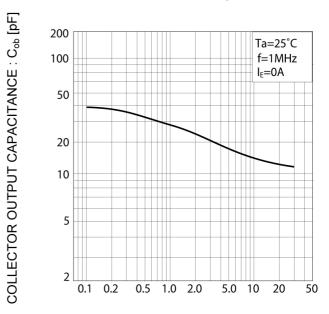


Fig.10 Collector Output Capacitance vs. Collector-Base Voltage



COLLECTOR-BASE VOLTAGE: V<sub>CB</sub> [V]

Fig.11 Emitter Input Capacitance vs. Emitter-Base Voltage

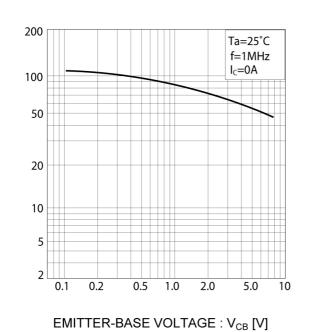
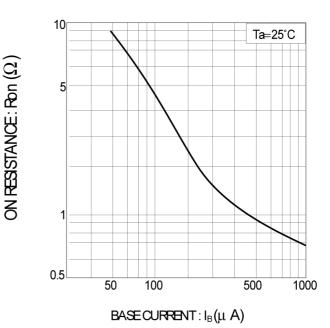


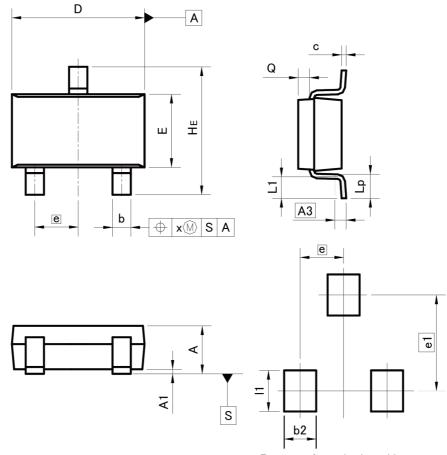
Fig.12 'ON' Resistance vs. Base Current Characteristics



EMITTER INPUT CAPACITANCE : Cip [pF]

### Dimensions

SMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM MILIMETERS			INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.00	1.30	0.039	0.051	
A1	0.00	0.10	0.000	0.004	
A3	0.:	25	0.0	0.010	
b	0.35	0.50	0.014	0.020	
С	0.09	0.25	0.004	0.010	
D	2.80	3.00	0.110	0.118	
E	1.50	1.80	0.059	0.071	
е	0.9	95	0.037		
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.20	0.30	0.008	0.012	
х	_	0.10	_	0.004	
у	_	0.10	_	0.004	

DIM	MILIM	ETERS	INCHES		
DIIVI	MIN	MAX	MIN	MAX	
b2	-	0.60	-	0.024	
e1	2.	10	0.0	83	
l1	-	0.90	ı	0.035	

Dimension in mm/inches



### Notes

- 1) The information contained herein is subject to change without notice.
- Before you use our Products, please contact our sales representative and verify the latest specifications:
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.

  Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communication, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.
- 7) The Products specified in this document are not designed to be radiation tolerant.
- 8) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative: transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
- Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 10) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 11) ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 12) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
- 13) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- 14) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact us.

## **ROHM Customer Support System**

http://www.rohm.com/contact/

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by ROHM manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE158 NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460
2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SD2150T100R SP000011176 FMMTA92QTA 2N2369ADCSM
2N5769 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E
US6T6TR NJL0281DG 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR MCH6102-TL-E
FP204-TL-E NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E NTE103 30A02MH-TL-E NSV40301MZ4T1G
NTE101 NTE13 NTE15